NSN 5961-01-275-0812

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-275-0812 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.120 inches **Overall Height:** 0.180 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 7 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open all transistor and 16.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 200.00 milliamperes collector current, dc all transistor **Power Rating Per Characteristic:** 750.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli